

Spec. No. : C337SC Issued Date : 2011.03.10 Revised Date : 2018.05.16

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5.0Amp. Surface Mount Schottky Barrier Diodes

SK520SC thru SK5100SC

Features

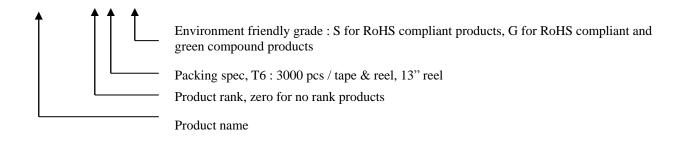
- For surface mounted applications.
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- Plastic material used carries Underwriters Laboratory Flammability Classification 94V-0
- Low leakage current
- High surge capability
- High temperature soldering: 250°C/10 seconds at terminals
- Exceeds environmental standards of MIL-S-19500/228

Mechanical Data

- Case: Molded plastic, SMC/JEDEC DO-214AB.
- Terminals: Solder plated, solderable per MIL-STD-750 method 2026
- Polarity: Indicated by cathode band.
- Mounting Position : Any.
- Weight: 0.195 gram, 0.00585 ounce

Ordering Information

Device	Package	Shipping	Marking
SK520SC- 0-T6-G			SS52
SK530SC- 0-T6-G			SS53
SK540SC- 0-T6-G	SMC		SS54
SK550SC- 0-T6-G	(Pb-free lead plating and halogen-free	3000 pcs / Tape & Reel	SS55
SK560SC- 0 -T6-G	package)		SS56
SK580SC-0-T6-G			SS58
SK5100SC-0-T6-G			S510





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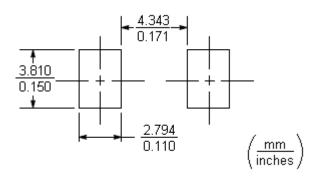
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Maximum Ratings and Electrical Characteristics

(Rating at 25°C ambient temperature unless otherwise specified.)

Donomatan	Crimbal	Type							I Indian
Parameter	Symbol	SK520	SK530	SK540	SK550	SK560	SK580	SK5100	Units
Repetitive peak reverse voltage	V _{RRM}	20	30	40	50	60	80	100	V
Maximum RMS voltage	V _{RMS}	14	21	28	35	42	56	70	V
Maximum DC blocking voltage	VR	20	30	40	50	60	80	100	V
Maximum instantaneous forward voltage, IF=5A (Note 1)	V_{F}	0.55	0.55	0.55	0.7	0.7	0.85	0.85	V
Average forward rectified current	Io	5				Α			
Peak forward surge current @8.3ms single half sine wave superimposed on rated load (JEDEC method)	Ifsm	м 150						A	
Maximum DC reverse current $V_R = V_{RRM}, T_A = 25^{\circ}C$ $V_R = V_{RRM}, T_A = 125^{\circ}C$	Ir	IR 0.5 50					mA mA		
Maximum thermal resistance, Junction to ambient	Rth,JA	Rth,JA 46					°C/W		
Maximum thermal resistance, Junction to case	R _{th} ,JC	R _{th,JC} 24						°C/W	
Diode junction capacitance @ f=1MHz and applied 4VDC reverse voltage	Сл	380(typ)					pF		
Storage temperature	Tstg	-55 ~ +150					$^{\circ}\!\mathbb{C}$		
Operating temperature	TJ	-55 ~ +125				$^{\circ}\!\mathbb{C}$			

Recommended soldering footprint

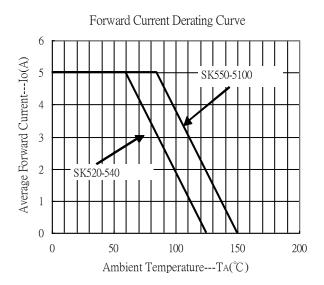




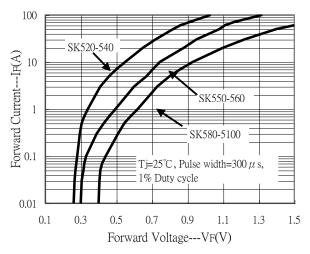
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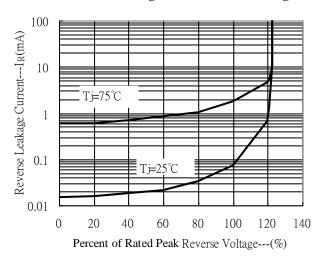
Characteristic Curves



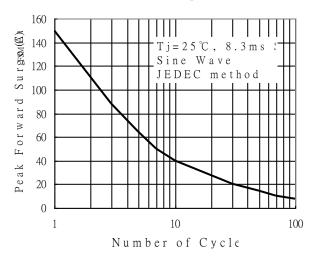
Forward Current vs Forward Voltage



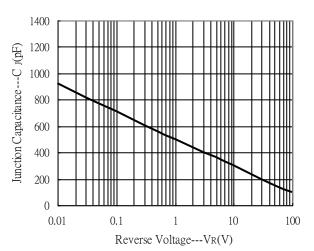
Reverse Leakage Current vs Reverse Voltage



Maximum Non-Repetitive Forw



Junction Capacitance vs Reverse Voltage

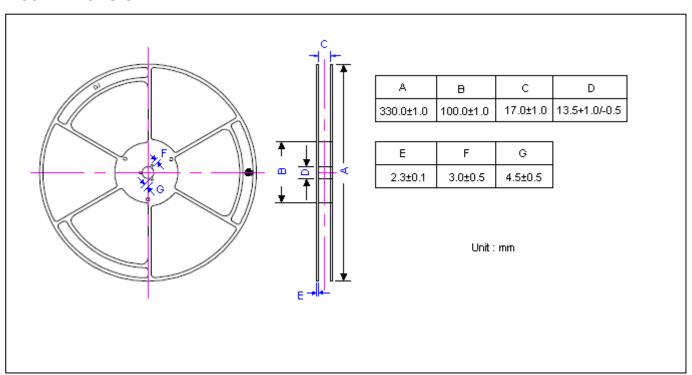




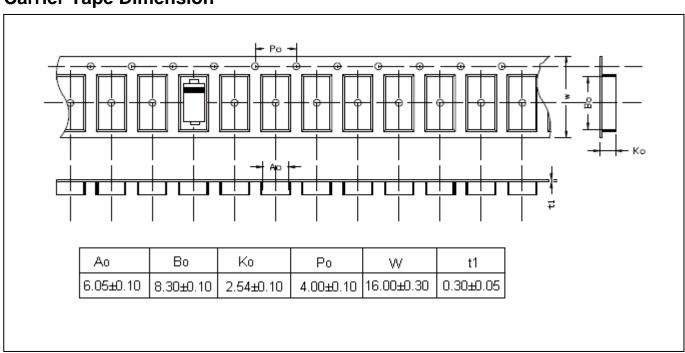
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Reel Dimension



Carrier Tape Dimension

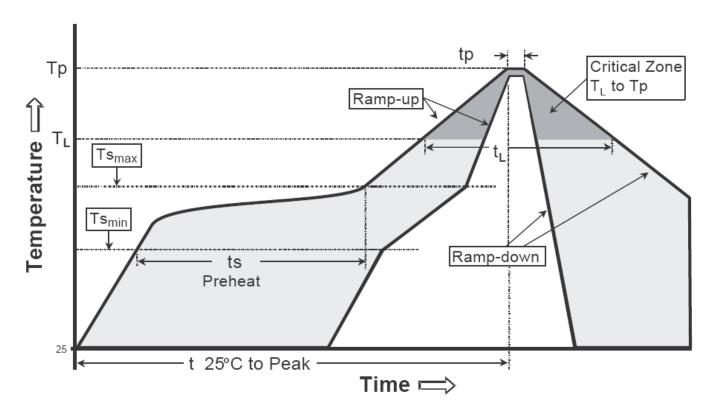




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Recommended temperature profile for IR reflow



Profile feature	Sn-Pb eutectic Assembly	Pb-free Assembly			
Average ramp-up rate (Tsmax to Tp)	3°C/second max.	3°C/second max.			
Preheat					
-Temperature Min(Ts min)	100°C	150°C			
-Temperature Max(Ts max)	150°C	200°C			
-Time(ts min to ts max)	60-120 seconds	60-180 seconds			
Time maintained above:					
-Temperature (T∟)	183°C	217°C			
- Time (t∟)	60-150 seconds	60-150 seconds			
Peak Temperature(T _P)	240 +0/-5 °C	260 +0/-5 °C			
Time within 5°C of actual peak temperature(tp)	10-30 seconds	20-40 seconds			
Ramp down rate	6°C/second max.	6°C/second max.			
Time 25 °C to peak temperature	6 minutes max.	8 minutes max.			

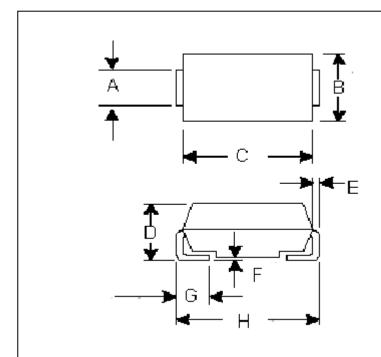
Note: All temperatures refer to topside of the package, measured on the package body surface.



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DO-214AB/SMC Dimension



DO-214AB/SMC Plastic Surface Mounted Package CYStek Package Code : SC

*:Typical

11,7,000									
DIM	Inches		Millimeters		DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.	וווט	Min.	Max.	Min.	Max.
Α	0.114	0.126	2.90	3.20	Е	0.006	0.012	0.15	0.31
В	0.220	0.245	5.59	6.22	F	0.004	0.008	0.10	0.20
С	0.260	0.280	6.60	7.11	G	0.030	0.060	0.76	1.52
D	0.078	0.103	1.98	2.62	Н	0.305	0.320	7.75	8.13

Notes: 1.Controlling dimension: millimeters.

2.Maximum lead thickness includes lead finish thickness, and minimum lead thickness is the minimum thickness of base material. 3.If there is any question with packing specification or packing method, please contact your local CYStek sales office.

Material:

• Lead : Pure tin plated.

• Mold Compound : Epoxy resin family, flammability solid burning class:UL94V-0.

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